Ultrafast Diode

50 A, 600 V

RURG5060

Description

The RURG5060 is an ultrafast diode with low forward voltage drop. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial application.

Features

- Ultrafast Recovery ($t_{rr} = 75 \text{ ns} (@ I_F = 50 \text{ A})$
- Max Forward Voltage($V_F = 1.6 V (@ T_C = 25 °C)$)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

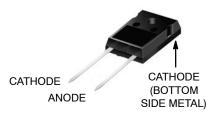
Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	600	V
Working Peak Reverse Voltage	V _{RWM}	600	V
DC Blocking Voltage	V _R	600	V
Average Rectified Forward Current ($T_C = 102 \ ^{\circ}C$)	I _{F(AV)}	50	A
Repetitive Peak Surge Current (Square Wave, 20 kHz)	I _{FRM}	100	A
Nonrepetitive Peak Surge Current (Halfwave 1 Phase, 60 Hz)	I _{FSM}	500	A
Maximum Power Dissipation	PD	150	W
Avalanche Energy (See Figure 7 and Figure 8)	E _{AVL}	40	mJ
Operating and Storage Temperature	T _{STG,} T _J	–65 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

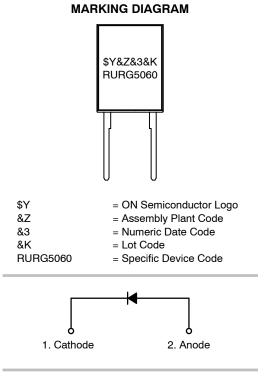


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JEDEC STYLE 2 LEAD TO-247 340CL



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

RURG5060

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Package	Brand	
RURG5060	TO-247-2L	RURG5060	

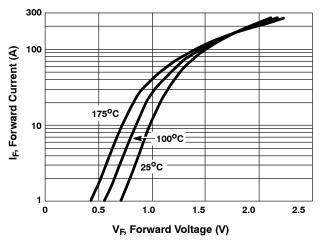
ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _F Instantaneous Forward Voltage (Pulse Width = 300 μs, Duty Cycle		I _F = 50 A			1.6	V
	(Puise Wiath = 300 µs, Duty Cycle = 2%)	I _F = 50 A, T _C = 150°C			1.4	V
I _R	Instantaneous Reverse Current	V _R = 600 V			250	μΑ
		V _R = 600 V T _C = 150°C			1.5	mA
	Reverse Recovery Time at dIF/dt = 100A/ $\!\mu s$ (See Figure 6) Summation of t_a + t_b	I _F = 1 A, dI _F /dt = 100 A/μs			65	ns
		I _F = 50 A, dI _F /dt = 100 A/μs			75	ns
t _a	Time to Reach Peak Reverse Current at dlF/dt = 100A/ μ s (See Figure 6)	l _F = 50 A, dI _F /dt = 100 A/μs		30		ns
t _b	Time from Peak I_{RM} to Projected Zero Crossing of I_{RM} Based on a Straight Line from Peak I_{RM} Through 25% of I_{RM} (See Figure 6)	I _F = 50 A, dI _F /dt = 100 A/μs		20		ns
$R_{\theta JC}$	Thermal Resistance Junction to Case				1.0	°C/W

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

RURG5060

TYPICAL PERFORMANCE CURVES





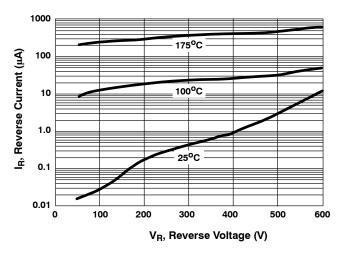


Figure 2. Reverse Current vs. Reverse Voltage

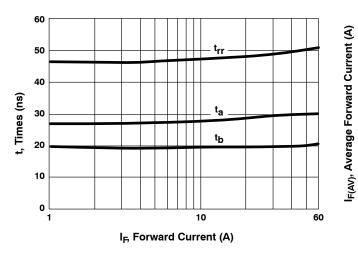


Figure 3. $T_{rr},\,t_a$ and t_b Curves vs. Forward Current

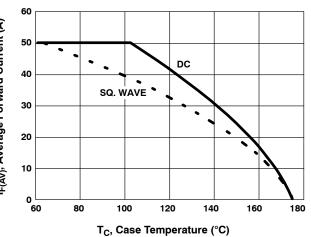
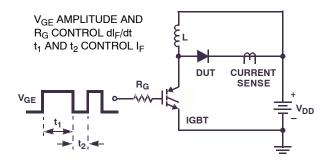


Figure 4. Current Derating Curve

RURG5060

TEST CIRCUITS AND WAVEFORMS





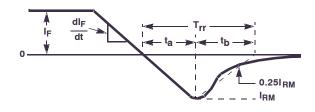


Figure 6. T_{rr} Waveforms and Definitions

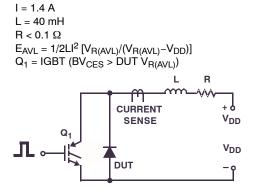


Figure 7. Avalanche Energy Test Circuit

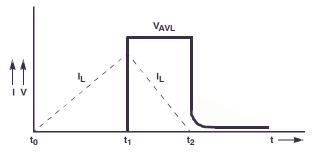


Figure 8. Avalanche Current and Voltage Waveforms

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MILLIMETERS

NOM

4.70

2.40

1.50

1.26

1.65

0.61

20.57

16.57

0.93

15.62

~

5.08

11.12

16.00

3.81

3.58

6.73

5.46

5.46

MAX

4.82

2.66

1.70

1.35

1.77

0.71

20.82

16.77

1.35

15.87

~

5.20

~

16.25

3.93

3.65

6.85

5.58

5.58

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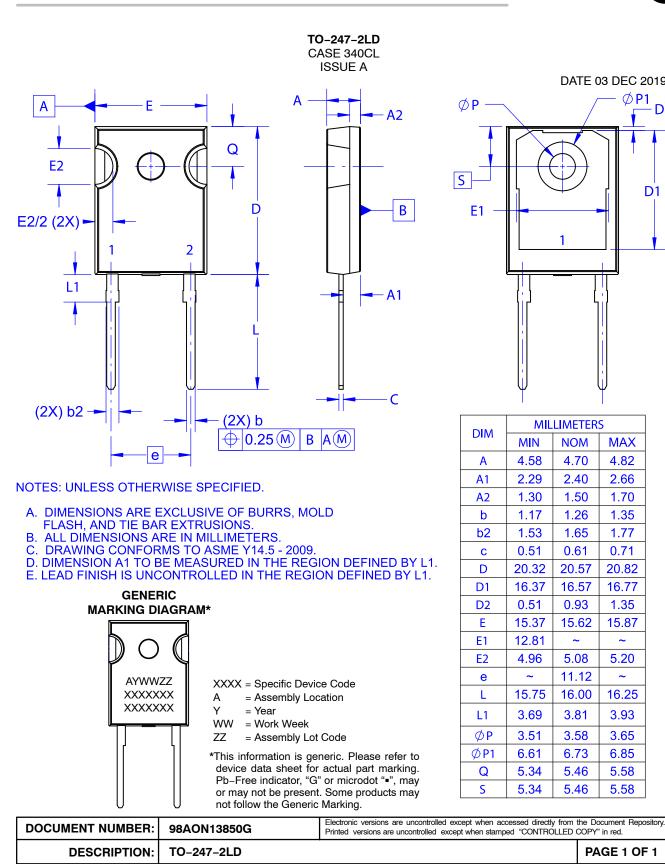
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